

# Rectifier Diode

## Types W2134NC300 to W2134NC400

Previous Type No.: SW26-36CXC635

**Absolute Maximum Ratings**

	<b>VOLTAGE RATINGS</b>	<b>MAXIMUM LIMITS</b>	<b>UNITS</b>
V <sub>RRM</sub>	Repetitive peak reverse voltage, (note 1)	3000-4000	V
V <sub>RSM</sub>	Non-repetitive peak reverse voltage, (note 1)	3100-4100	V

	<b>OTHER RATINGS</b>	<b>MAXIMUM LIMITS</b>	<b>UNITS</b>
I <sub>F(AV)M</sub>	Maximum average forward current, T <sub>sink</sub> =55°C, (note 2)	2134	A
I <sub>F(AV)M</sub>	Maximum average forward current, T <sub>sink</sub> =100°C, (note 2)	1494	A
I <sub>F(RMS)M</sub>	Nominal RMS forward current, T <sub>sink</sub> =25°C, (note 2)	3910	A
I <sub>F(d.c.)</sub>	D.C. forward current, T <sub>sink</sub> =25°C, (note 3)	3472	A
I <sub>FSM</sub>	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>rm</sub> =60%V <sub>RRM</sub> , (note 4)	20.0	kA
I <sub>FSM2</sub>	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>rm</sub> ≤10V, (note 4)	24.0	kA
I <sup>2</sup> t	I <sup>2</sup> t capacity for fusing t <sub>p</sub> =10ms, V <sub>rm</sub> =60%V <sub>RRM</sub> , (note 4)	2.0×10 <sup>6</sup>	A <sup>2</sup> s
I <sup>2</sup> t	I <sup>2</sup> t capacity for fusing t <sub>p</sub> =10ms, V <sub>rm</sub> ≤10V, (note 4)	2.88×10 <sup>6</sup>	A <sup>2</sup> s
T <sub>j op</sub>	Operating temperature range	-55 to +160	°C
T <sub>stg</sub>	Storage temperature range	-55 to +190	°C

Notes:-

- 1) De-rating factor of 0.13% per °C is applicable for T<sub>j</sub> below 25°C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Double side cooled.
- 4) Half-sinewave, 160°C T<sub>j</sub> initial.

### Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V <sub>FM</sub>	Maximum peak forward voltage	-	-	1.86	I <sub>FM</sub> =3800A	V
V <sub>T0</sub>	Threshold voltage	-	-	0.865		V
r <sub>T</sub>	Slope resistance	-	-	0.26		mΩ
I <sub>R<sub>RRM</sub></sub>	Peak reverse current	-	-	50	Rated V <sub>RRM</sub>	mA
R <sub>thJK</sub>	Thermal resistance, junction to heatsink	-	-	0.022	Double side cooled	K/W
		-	-	0.044	Single side cooled	K/W
F	Mounting force	19	-	26	Note 2	kN
W <sub>t</sub>	Weight		480			g

Notes:-

- 1) Unless otherwise indicated T<sub>j</sub>=160°C.
- 2) For other clamp forces, please consult factory.

## Notes on Ratings and Characteristics

### 1.0 Voltage Grade Table

Voltage Grade	$V_{RRM}$ V	$V_{RSM}$ V	$V_R$ DC V
30	3000	3100	1750
40	4000	4100	2000

### 2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

### 3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for  $T_j$  below 25°C.

### 4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

### 5.0 Computer Modelling Parameters

#### 5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T} \quad \text{and:} \quad W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{j \max} - T_K$$

Where  $V_{T0}=0.865V$ ,  $r_T=0.26m\Omega$ ,

$R_{th}$  = Supplementary thermal impedance, see table below and

$ff$  = Form factor, see table below.

Supplementary Thermal Impedance				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave Double Side Cooled	0.0320	0.0274	0.0253	0.022
Square wave Cathode Side Cooled	0.0540	0.0497	0.0477	0.044
Sine wave Double Side Cooled	0.0271	0.0229	0.022	
Sine wave Cathode Side Cooled	0.0496	0.0467	0.044	

Form Factors				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	2.449	1.732	1.414	1
Sine wave	2.778	1.879	1.57	

## 5.2 Calculating $V_F$ using ABCD Coefficients

The on-state characteristic  $I_F$  vs.  $V_F$ , on page 8 is represented in two ways;

- (i) the well established  $V_{T0}$  and  $r_T$  tangent used for rating purposes and
- (ii) a set of constants A, B, C, D, forming the coefficients of the representative equation for  $V_F$  in terms of  $I_F$  given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for  $V_F$  agree with the true device characteristic over a current range, which is limited to that plotted.

25°C Coefficients		160°C Coefficients	
A	1.075751	A	0.7000012
B	-0.01870484	B	0.04239071
C	$0.1119432 \times 10^{-3}$	C	$0.2948272 \times 10^{-3}$
D	$4.173847 \times 10^{-3}$	D	$-5.121299 \times 10^{-3}$

## 5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left( 1 - e^{\frac{-t}{\tau_p}} \right)$$

Where  $p = 1$  to  $n$ ,  $n$  is the number of terms in the series and:

$t$  = Duration of heating pulse in seconds.

$r_t$  = Thermal resistance at time  $t$ .

$r_p$  = Amplitude of  $p$ th term.

$\tau_p$  = Time Constant of  $r$ th term.

The coefficients for this device are shown in the tables below:

D.C. Double Side Cooled					
Term	1	2	3	4	5
$r_p$	0.01155655	$5.055660 \times 10^{-3}$	$2.503056 \times 10^{-3}$	$1.549315 \times 10^{-3}$	$1.736643 \times 10^{-3}$
$\tau_p$	0.9222825	0.1703512	0.0453273	0.01143316	0.01582146

D.C. Single Side Cooled						
Term	1	2	3	4	5	6
$r_p$	0.0280202	$4.27556 \times 10^{-3}$	$5.20318 \times 10^{-3}$	$3.71583 \times 10^{-3}$	$2.00592 \times 10^{-3}$	$1.70787 \times 10^{-3}$
$\tau_p$	5.445791	2.121661	0.248842	0.0761462	0.0140677	0.0171541

**Curves**

Figure 1 – Mean forward current vs. power dissipation– Double side cooled

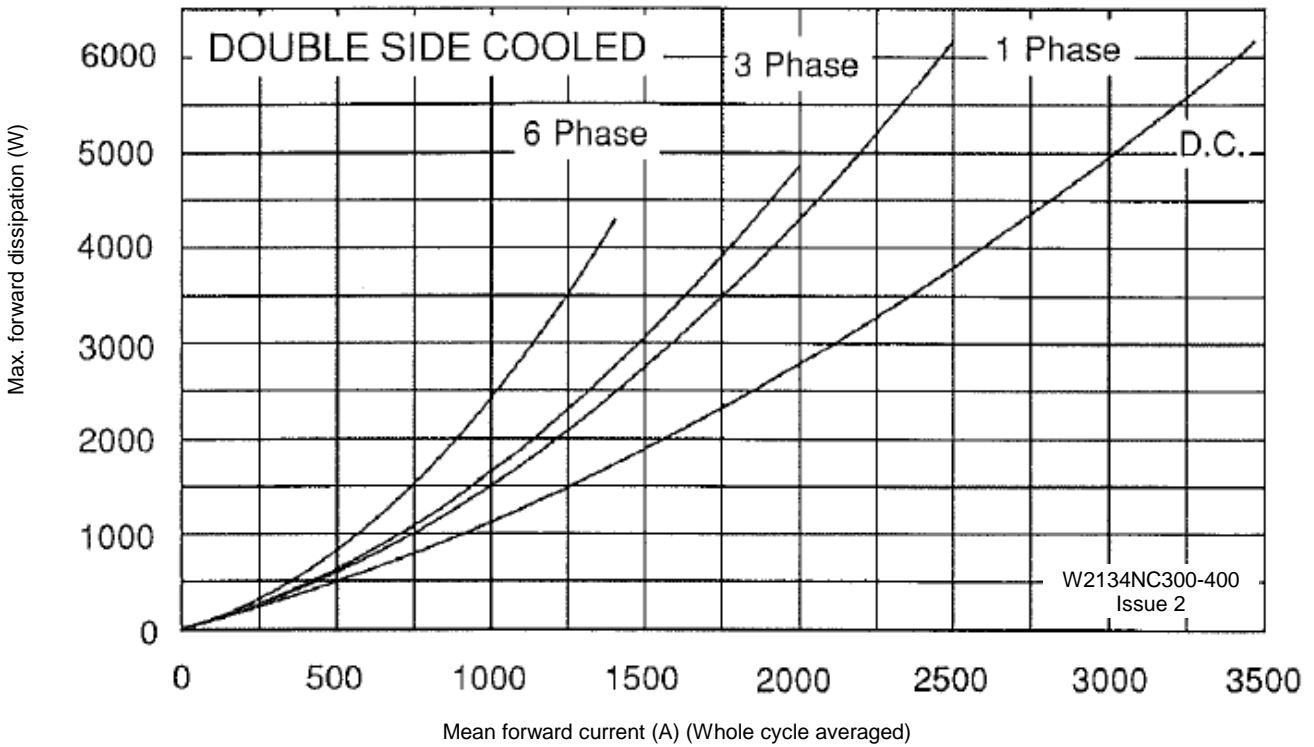


Figure 2 – Mean forward current vs. power dissipation – Single side cooled

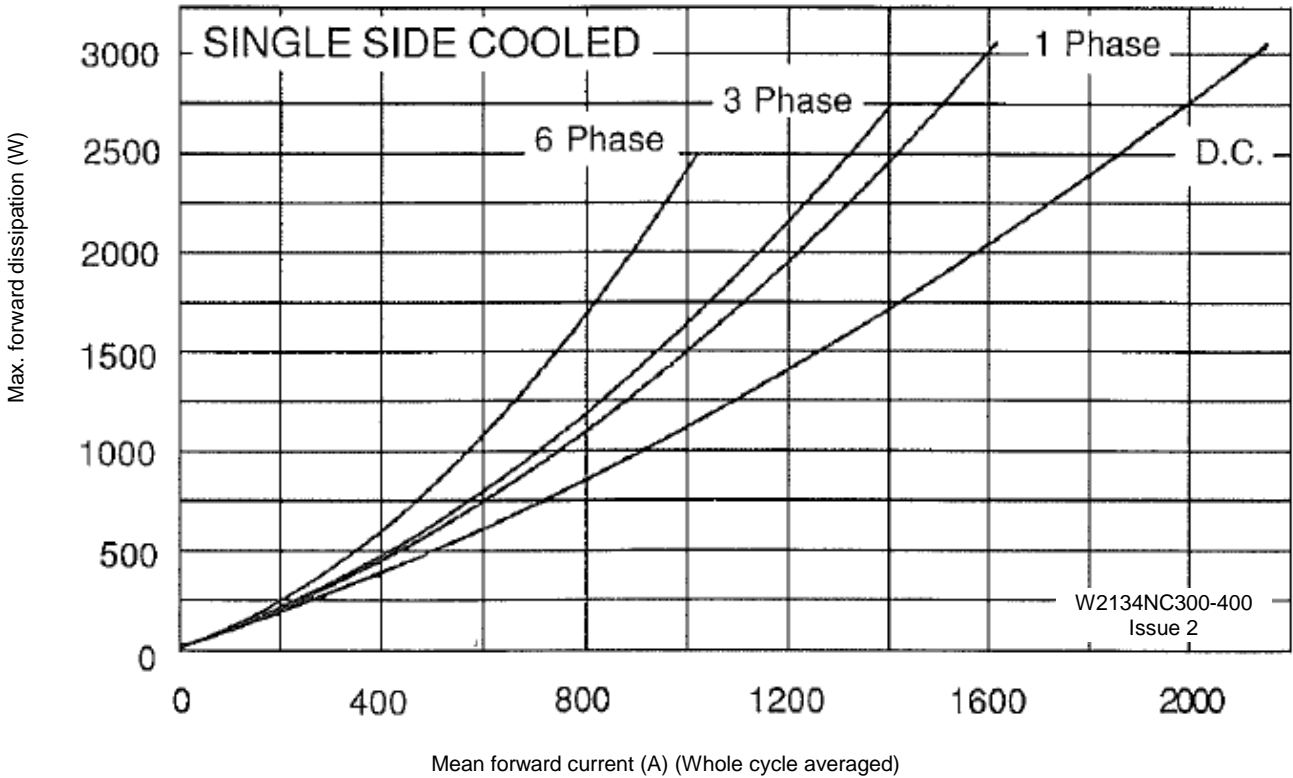


Figure 3 – Max. heatsink temperature vs. mean forward current – Double side cooled

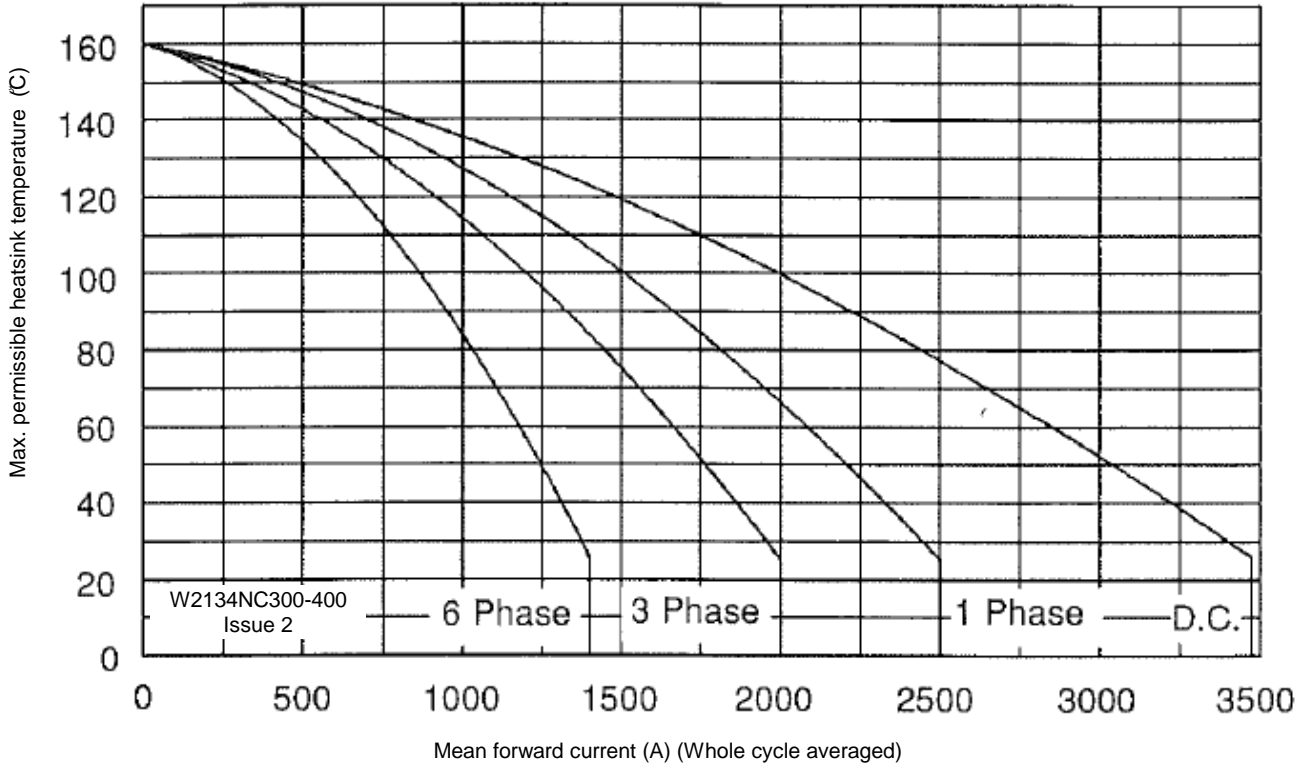


Figure 4 – Max. heatsink temperature vs. mean forward current – Single side cooled

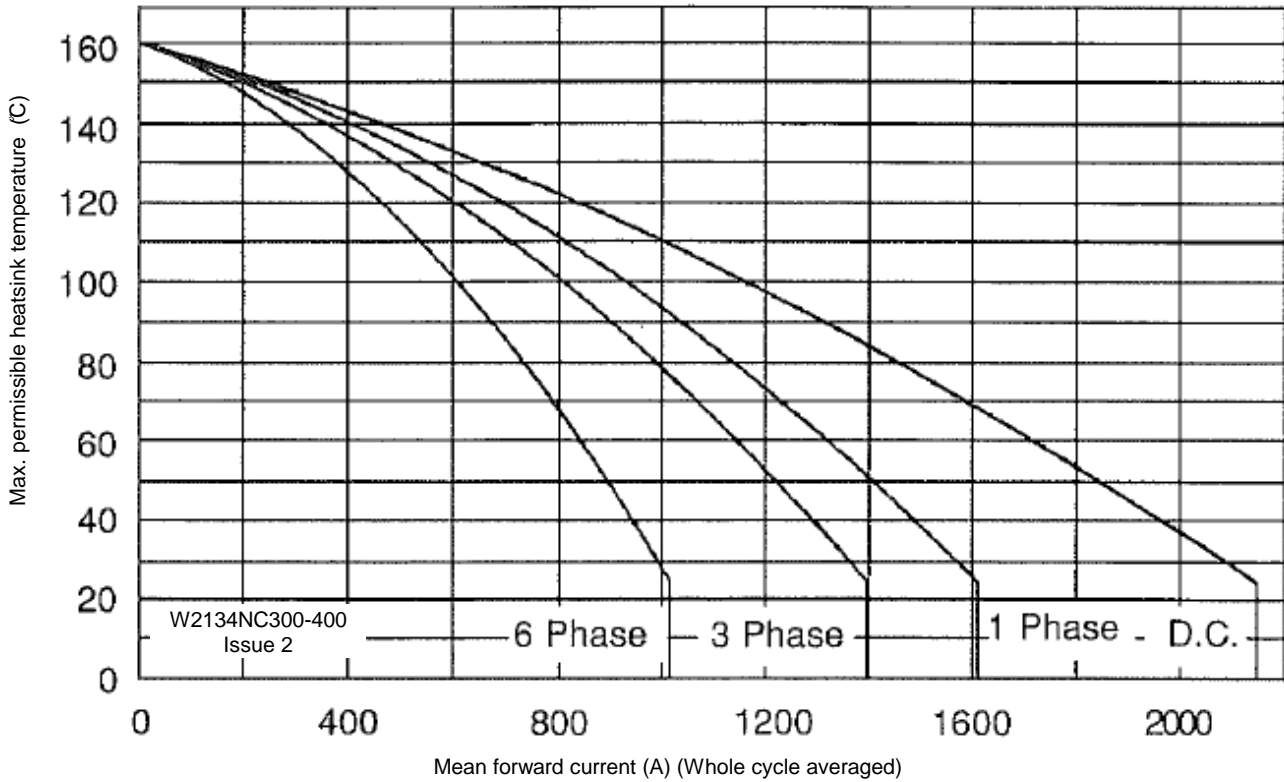


Figure 5 – Forward characteristics of limit device

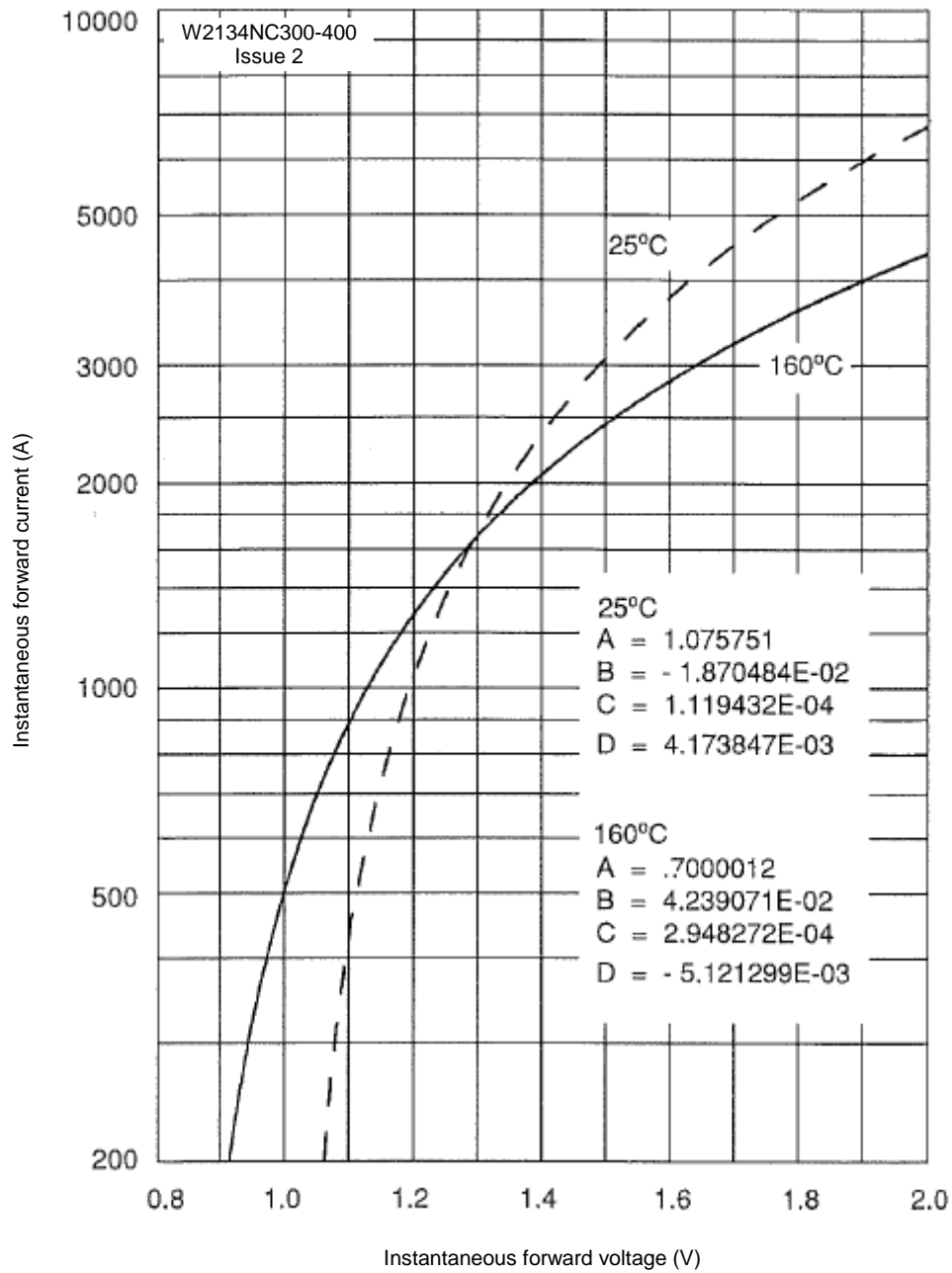




Figure 6 – Transient thermal impedance

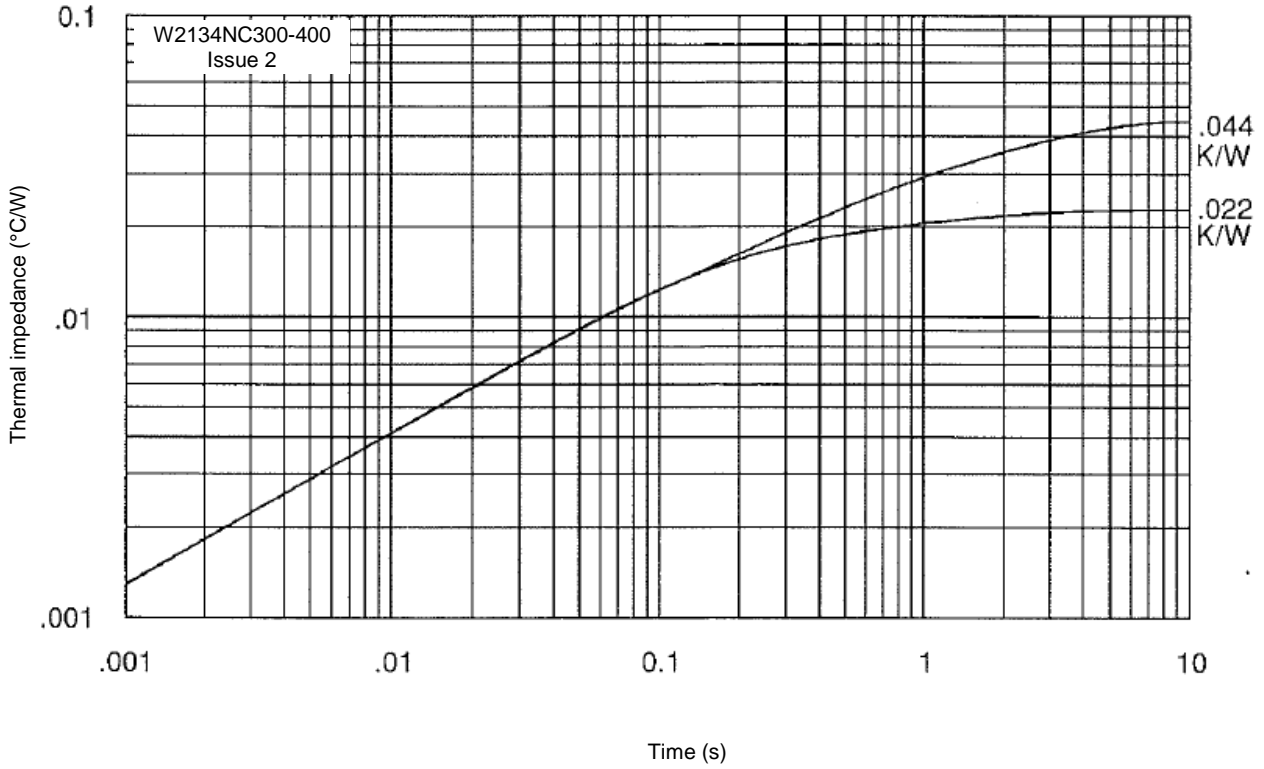
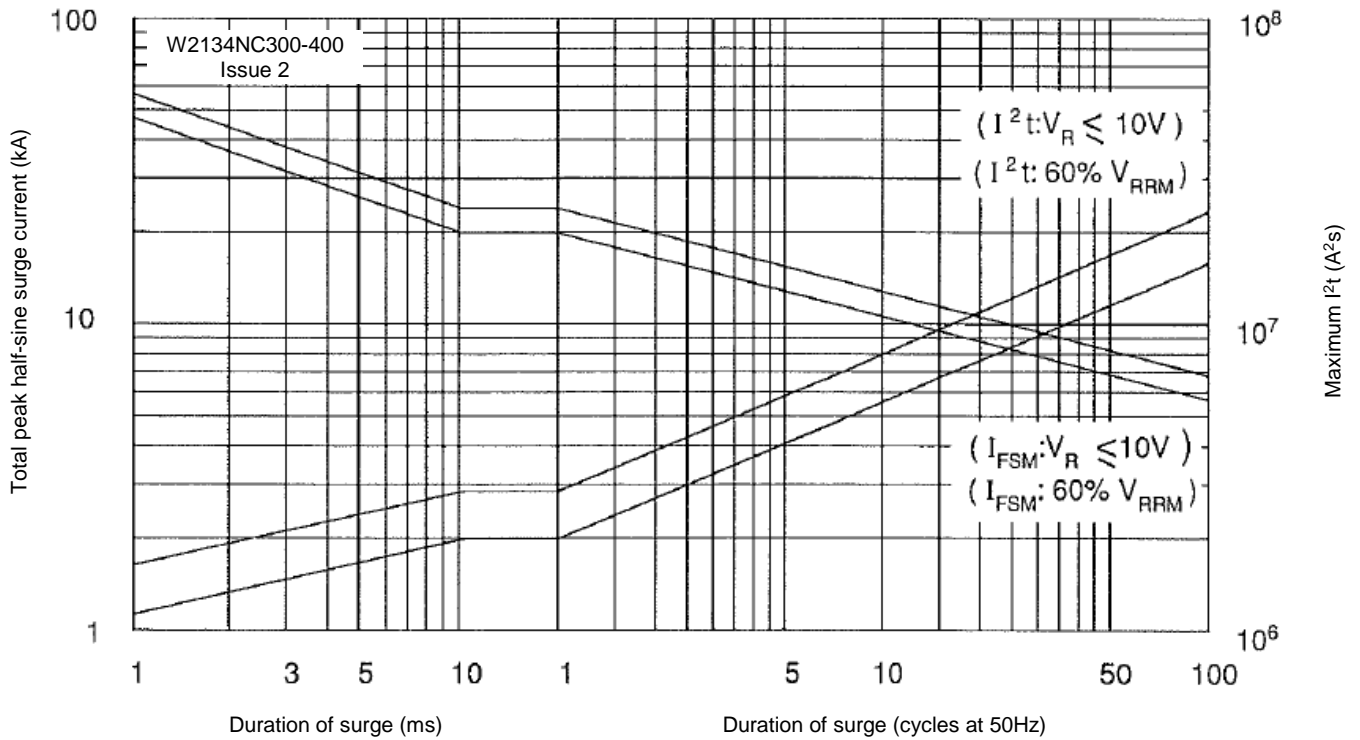
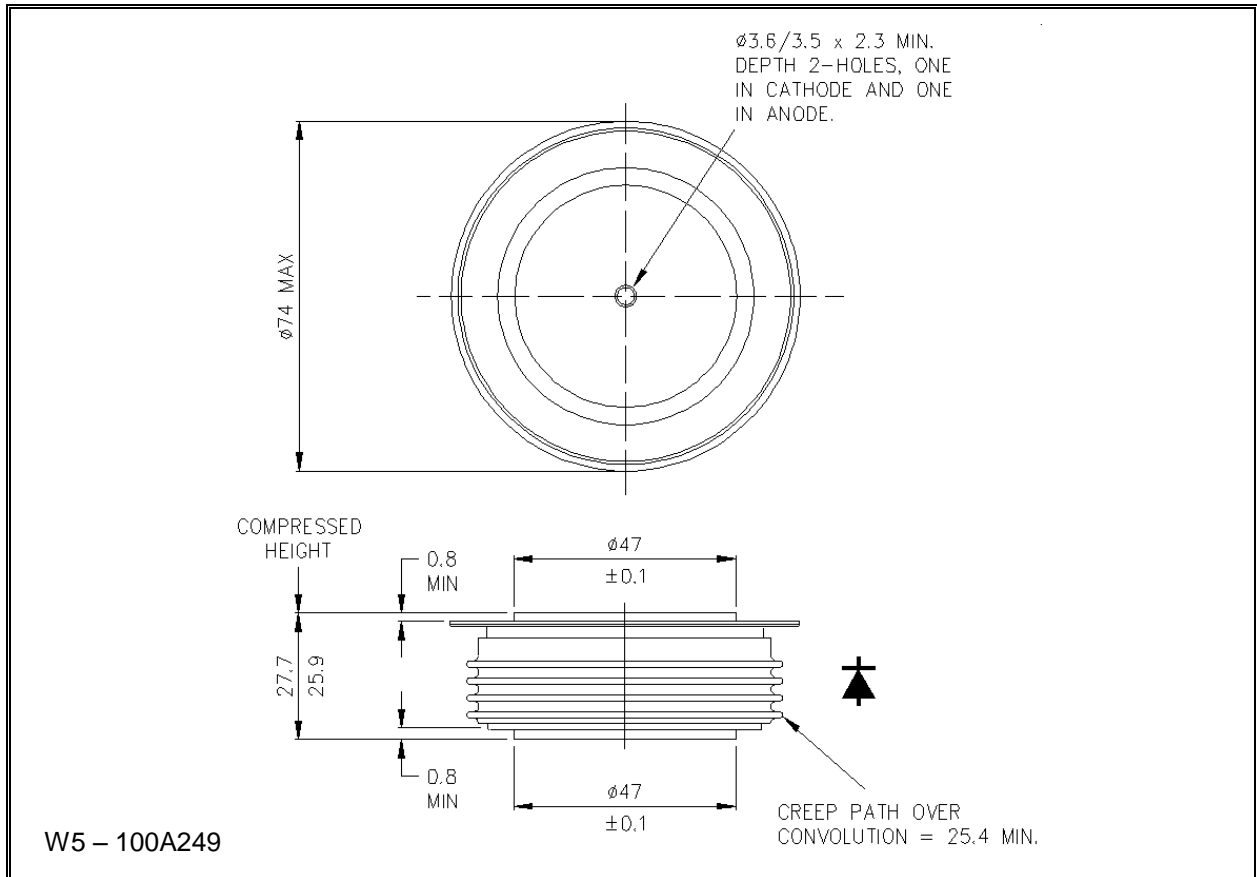


Figure 7 – Maximum non-repetitive surge current at initial junction temperature 160°C



**Outline Drawing & Ordering Information**



**ORDERING INFORMATION** (Please quote 10 digit code as below)

<b>W2134</b>	<b>NC</b>	<b>◆◆</b>	<b>0</b>
Fixed Type Code	Fixed Outline Code	Voltage code $V_{RRM}/100$ 30-40	Fixed code

Order code: W2134NC400 – 4000V  $V_{RRM}$ , 27mm clamp height capsule.

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